

## NCE N-Channel Enhancement Mode Power MOSFET

## **Description**

The NCE2302 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

#### **General Features**

● V<sub>DS</sub> = 20V,I<sub>D</sub> =4A

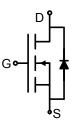
 $R_{DS(ON)}$  < 59m $\Omega$  @  $V_{GS}$ =2.5V

 $R_{DS(ON)}$  < 45m $\Omega$  @  $V_{GS}$ =4.5V

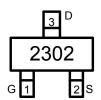
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

### **Application**

- Battery protection
- Load switch
- Power management



Schematic diagram



Marking and pin assignment



SOT-23 top view

## **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2302	NCE2302	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	20	V
Gate-Source Voltage	V <sub>GS</sub>	±12	V
Drain Current-Continuous	I <sub>D</sub>	4	Α
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	10	Α
Maximum Power Dissipation	P <sub>D</sub>	1	W
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	℃

## **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	125	°C/W

### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	20	22	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =20V,V <sub>GS</sub> =0V	-	-	1	μA



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# NCE2302

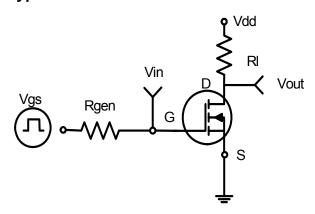
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=250\mu A$	0.5	0.85	1.2	V
Desir Course On Chata Resistance		V <sub>GS</sub> =2.5V, I <sub>D</sub> =2.5A	-	37	59	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =2.9A	-	30	45	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =2.9A	-	8	-	S
Dynamic Characteristics (Note4)	,		•	l .		•
Input Capacitance	C <sub>lss</sub>	V <sub>DS</sub> =10V,V <sub>GS</sub> =0V,	-	300	-	PF
Output Capacitance	Coss		-	120	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	80	-	PF
Switching Characteristics (Note 4)			•			•
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =10V,I <sub>D</sub> =2.9A	-	10	15	nS
Turn-on Rise Time	t <sub>r</sub>		-	50	85	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =4.5 $V$ , $R_{GEN}$ =6 $\Omega$	-	17	45	nS
Turn-Off Fall Time	t <sub>f</sub>		-	10	20	nS
Total Gate Charge	Qg	V <sub>DS</sub> =10V,I <sub>D</sub> =2.9A,	-	4.0	10	nC
Gate-Source Charge	Q <sub>gs</sub>		-	0.65	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =4.5V	-	1.2	-	nC
Drain-Source Diode Characteristics	,		•	1		1
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =2.9A	-	0.75	1.2	V
Diode Forward Current (Note 2)	Is		-	-	4	Α

### Notes:

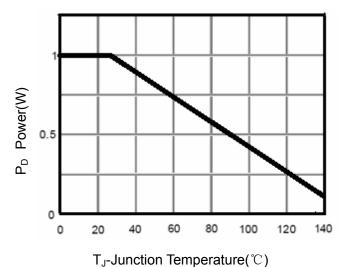
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



## **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 



**Figure 3 Power Dissipation** 

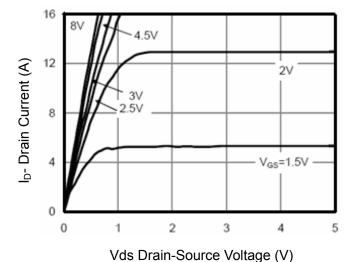
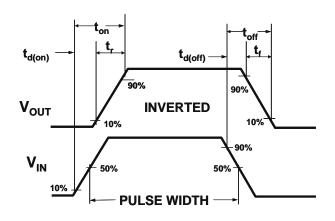
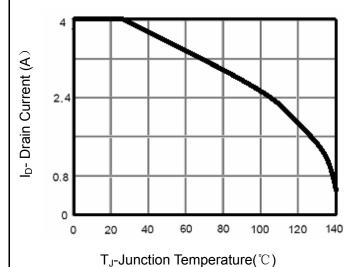


Figure 5 Output Characteristics



**Figure 2:Switching Waveforms** 



**Figure 4 Drain Current** 

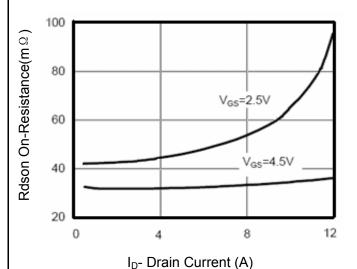
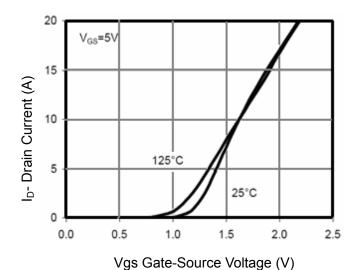
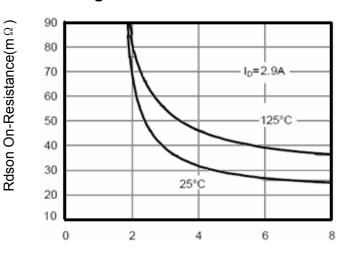


Figure 6 Drain-Source On-Resistance





**Figure 7 Transfer Characteristics** 



Vgs Gate-Source Voltage (V)

Figure 9 Rdson vs Vgs

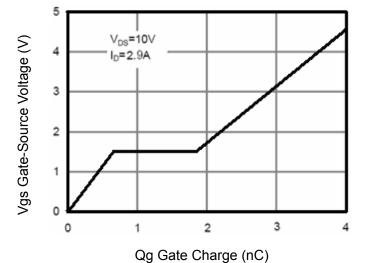
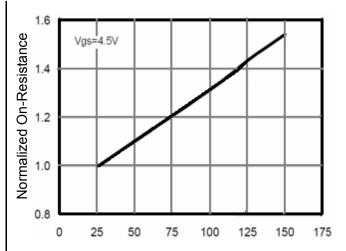
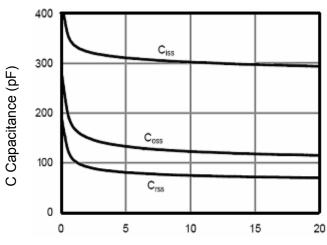


Figure 11 Gate Charge



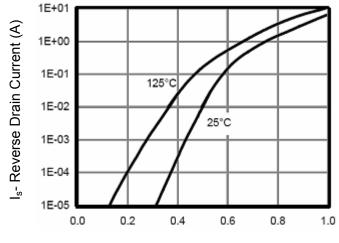
 $T_J$ -Junction Temperature( $^{\circ}$ C)





Vds Drain-Source Voltage (V)

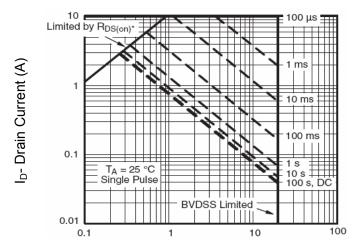
Figure 10 Capacitance vs Vds



Vsd Source-Drain Voltage (V)

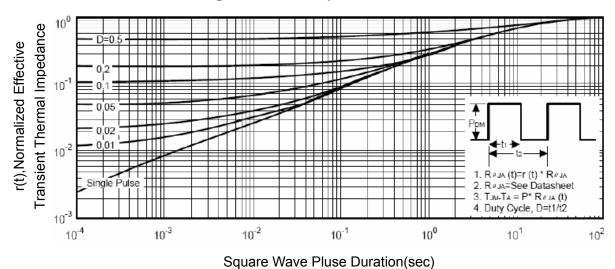
Figure 12 Source- Drain Diode Forward





Vds Drain-Source Voltage (V)

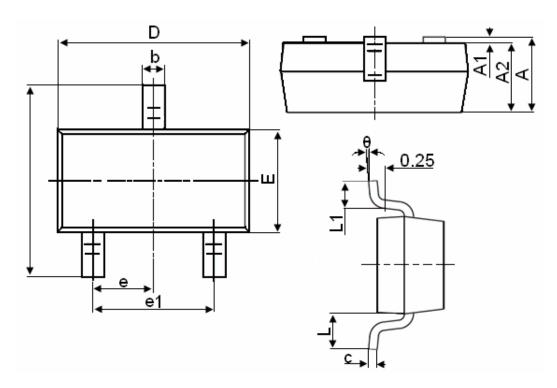
**Figure 13 Safe Operation Area** 



**Figure 14 Normalized Maximum Transient Thermal Impedance** 



# **SOT-23 Package Information**



Symbol	Dimensions in Millimeters				
Symbol	MIN.	MAX.			
Α	0.900	1.150			
A1	0.000	0.100			
A2	0.900	1.050			
b	0.300	0.500			
С	0.080	0.150			
D	2.800	3.000			
Е	1.200	1.400			
E1	2.250	2.550			
е		0.950TYP			
e1	1.800	2.000			
L	0.550REF				
L1	0.300	0.500			
θ	0°	8°			

### Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$



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